NSN 5961-01-359-0311

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-359-0311 **Inclosure Material:** Plastic **Overall Length:** 0.722 inches **Overall Height:** 0.300 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-116 **Component Name And Quantity:** 4 transistor **Mounting Method: Terminal Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 30.0 collector to emitter voltage/static/base open all transistor and 60.0 collector to base voltage/static/emitter open all transistor and 5.0 emitter to base voltage, static, collector open all transistor **Current Rating Per Characteristic:** 500.00 milliamperes source cutoff current all transistor **Power Rating Per Characteristic:** 650.0 milliwatts small-signal input power, common-collector preset all transistor **Transfer Ratio:** 30.0 static forward current transfer ratio, common-emitter all transistor **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Terminal Type And Quantity:** 14 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: